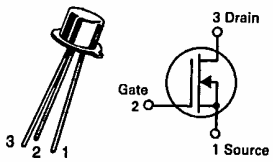
2N3796
2N3797

CASE 22-03, STYLE 2
TO-18 (TO-206AA)



MOSFETs
LOW POWER AUDIO

N-CHANNEL — DEPLETION

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage 2N3796 2N3797	V_{DS}	 25 20	Vdc
Gate-Source Voltage	V_{GS}	±10	Vdc
Drain Current	I_D	20	mAdc
Total Device Dissipation @ T_A = 25°C Derate above 25°C	P_D	200 1.14	mW mW/°C
Junction Temperature Range	T_J	+175	°C
Storage Channel Temperature Range	T_{stg}	−65 to +200	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage (V_{GS} = −4.0 V, I_D = 5.0 μA) (V_{GS} = −7.0 V, I_D = 5.0 μA)	 2N3796 2N3797	$V_{(BR)DSX}$	 25 20	 30 25	 — —	Vdc
Gate Reverse Current(1) (V_{GS} = −10 V, V_{DS} = 0) (V_{GS} = −10 V, V_{DS} = 0, T_A = 150°C)		I_{GSS}	 — —	 — —	 1.0 200	pAdc
Gate Source Cutoff Voltage (I_D = 0.5 μA, V_{DS} = 10 V) (I_D = 2.0 μA, V_{DS} = 10 V)	 2N3796 2N3797	$V_{GS(off)}$	 — —	 −3.0 −5.0	 −4.0 −7.0	Vdc
Drain-Gate Reverse Current(1) (V_{DG} = 10 V, I_S = 0)		I_{DGO}	—	—	1.0	pAdc
ON CHARACTERISTICS						
Zero-Gate-Voltage Drain Current (V_{DS} = 10 V, V_{GS} = 0)	 2N3796 2N3797	I_{DSS}	 0.5 2.0	 1.5 2.9	 3.0 6.0	mAdc
On-State Drain Current (V_{DS} = 10 V, V_{GS} = +3.5 V)	 2N3796 2N3797	$I_{D(on)}$	 7.0 9.0	 8.3 14	 14 18	mAdc
SMALL-SIGNAL CHARACTERISTICS						
Forward Transfer Admittance (V_{DS} = 10 V, V_{GS} = 0, f = 1.0 kHz) (V_{DS} = 10 V, V_{GS} = 0, f = 1.0 MHz)	 2N3796 2N3797 2N3796 2N3797	$\lvert Y_{fs}\rvert$	 900 1500 900 1500	 1200 2300 — —	 1800 3000 — —	μmhos
Output Admittance (V_{DS} = 10 V, V_{GS} = 0, f = 1.0 kHz)	 2N3796 2N3797	$\lvert Y_{os}\rvert$	 — —	 12 27	 25 60	μmhos
Input Capacitance (V_{DS} = 10 V, V_{GS} = 0, f = 1.0 MHz)	 2N3796 2N3797	C_{iss}	 — —	 5.0 6.0	 7.0 8.0	pF
Reverse Transfer Capacitance (V_{DS} = 10 V, V_{GS} = 0, f = 1.0 MHz)		C_{rss}	—	0.5	0.8	pF
FUNCTIONAL CHARACTERISTICS						
Noise Figure (V_{DS} = 10 V, V_{GS} = 0, f = 1.0 kHz, R_S = 3 megohms)		NF	—	3.8	—	dB

(1) This value of current includes both the FET leakage current as well as the leakage current associated with the test socket and fixture when measured under best attainable conditions.

TYPICAL DRAIN CHARACTERISTICS

FIGURE 1 — 2N3796

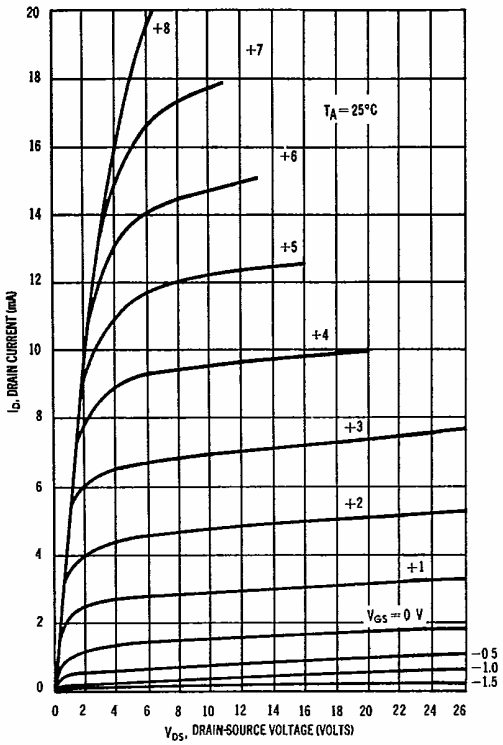
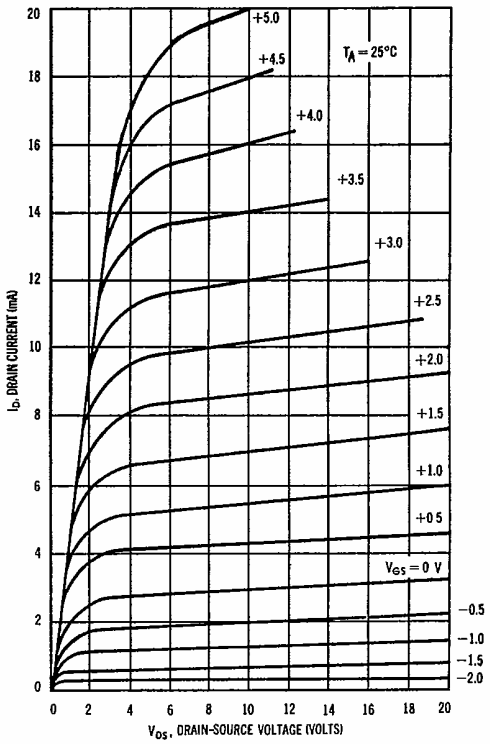


FIGURE 2 — 2N3797



COMMON SOURCE TRANSFER CHARACTERISTICS

FIGURE 3 — 2N3796

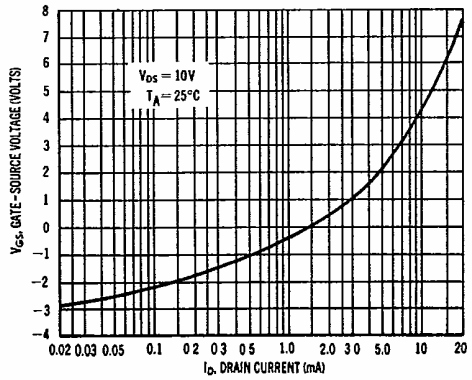


FIGURE 4 — 2N3797

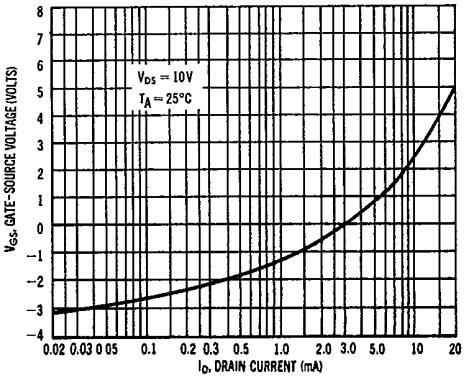


FIGURE 5 — FORWARD TRANSFER ADMITTANCE

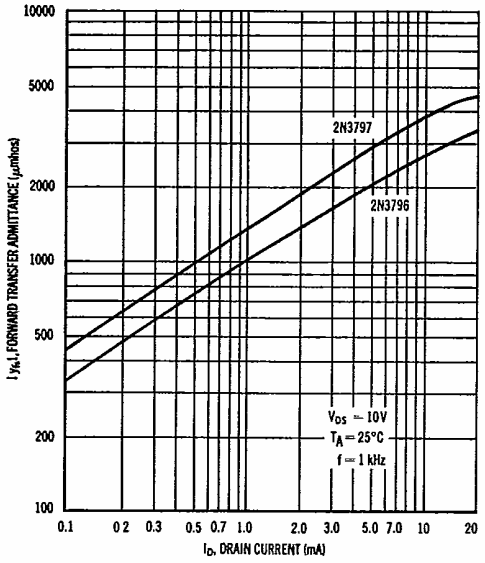


FIGURE 6 — OUTPUT ADMITTANCE

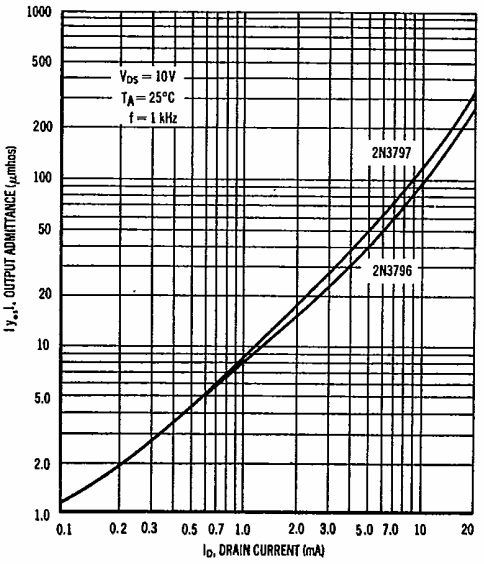


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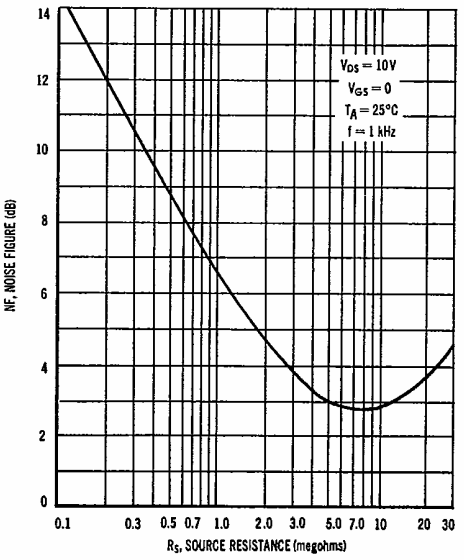
FIGURE 7 — NOISE FIGURE



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